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NTE7410 Integrated Circuit TTL – Triple 3–Input Positive NAND Gate

Description:

The NTE7410 contains three independent 3–Input NAND gates in a 14–Lead plastic DIP type package.

Absolute Maximum Ratings: (Note 1)

| | |
|--|-----------------|
| Supply Voltage, V_{CC} | 7V |
| DC Input Voltage, V_{IN} | 5.5V |
| Operating Temperature Range, T_A | 0°C to +70°C |
| Storage Temperature Range, T_{STG} | -65°C to +150°C |

Note 1. Unless otherwise specified, all voltages are referenced to GND.

Recommended Operating Conditions:

| Parameter | Symbol | Min | Typ | Max | Unit |
|-----------------------------|----------|------|-----|------|------|
| Supply Voltage | V_{CC} | 4.75 | 5.0 | 5.25 | V |
| High–Level Input Voltage | V_{IH} | 2.0 | – | – | V |
| Low–Level Input Voltage | V_{IL} | – | – | 0.8 | V |
| High–Level Output Current | I_{OH} | – | – | -0.4 | mA |
| Low–Level Output Current | I_{OL} | – | – | 16 | mA |
| Operating Temperature Range | T_A | 0 | – | +70 | °C |

Electrical Characteristics: (Note 2, Note 3)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|---------------------------|----------|---|-----|-----|------|------|
| Input Clamp Voltage | V_{IK} | $V_{CC} = \text{MIN}$, $I_I = -12\text{mA}$ | – | – | -1.5 | V |
| High Level Output Voltage | V_{OH} | $V_{CC} = \text{MIN}$, $V_{IL} = 0.8\text{V}$, $I_{OH} = -0.4\text{mA}$ | 2.4 | 3.4 | – | V |
| Low Level Output Voltage | V_{OL} | $V_{CC} = \text{MIN}$, $V_{IH} = 2\text{V}$, $I_{OL} = 16\text{mA}$ | – | 0.2 | 0.4 | V |
| Input Current | I_I | $V_{CC} = \text{MAX}$, $V_I = 5.5\text{V}$ | – | – | 1 | mA |

Note 2. For conditions shown as MIN or MAX, use the appropriate value specified under "Recommended Operation Conditions".

Note 3. All typical values are at $V_{CC} = 5\text{V}$, $T_A = +25^\circ\text{C}$.

Electrical Characteristics (Cont'd): (Note 2, Note 3)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|------------------------------|------------------|--|-----|-----|------|------|
| High Level Input Current | I _{IH} | V _{CC} = MAX, V _I = 2.4V | - | - | 40 | µA |
| Low Level Input Current | I _{IL} | V _{CC} = MAX, V _I = 0.4V | - | - | -1.6 | mA |
| Short-Circuit Output Current | I _{OS} | V _{CC} = MAX, Note 4 | -18 | - | -55 | mA |
| High Level Supply Current | I _{CCH} | V _{CC} = MAX, V _I = 0 | - | 3 | 6 | mA |
| Low Level Supply Current | I _{CCL} | V _{CC} = MAX, V _I = 4.5V | - | 9.0 | 16.5 | mA |

Note 2. For conditions shown as MIN or MAX, use the appropriate value specified under "Recommended Operation Conditions".

Note 3. All typical values are at V_{CC} = 5V, T_A = +25°C.

Note 4. Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed one second.

Switching Characteristics: (V_{CC} = 5V, T_A = +25°C unless otherwise specified)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|------------------|--|-----|-----|-----|------|
| Propagation Delay Time From A, B or C Input to Y Output | t _{PLH} | R _L = 400Ω, C _L = 15pF | - | 11 | 22 | ns |
| | t _{PHL} | | - | 7 | 15 | ns |

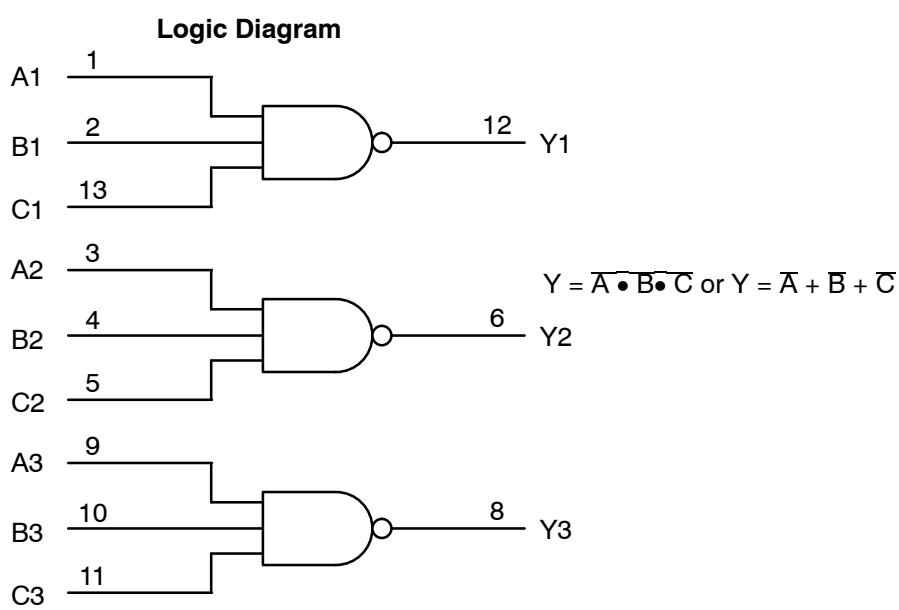
Function Table (Each Gate):

| Inputs | | | Output |
|--------|---|---|--------|
| A | B | C | Y |
| H | H | H | L |
| L | X | X | H |
| X | L | X | H |
| X | X | L | H |

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care



Pin 14 = V_{CC}
Pin 7 = GND

Pin Connection Diagram

